

Subject card

| Subject name and code | Solid state electronics and nanoelectronics, PG_00037203 | | | | | | | | |
|---|---|--|---|----------------|------------------------|---|---------|-----|--|
| Field of study | Nanotechnology | | | | | | | | |
| Date of commencement of studies | October 2021 | | Academic year of realisation of subject | | | 2024/2025 | | | |
| Education level | first-cycle studies | | Subject group | | | Optional subject group Subject group related to scientific research in the field of study | | | |
| Mode of study | Full-time studies | | Mode of delivery | | | at the university | | | |
| Year of study | 4 | | Language of instruction | | | Polish | | | |
| Semester of study | 7 | | ECTS credits | | 4.0 | | | | |
| Learning profile | general academic profile | | Assessme | ssessment form | | assessment | | | |
| Conducting unit | Department of Solid State Physics -> Faculty of Applied Physics and Mathematics | | | | | | | | |
| Name and surname | Subject supervisor | prof. dr hab. inż. Barbara Kościelska | | | | | | | |
| of lecturer (lecturers) | Teachers | | prof. dr hab. inż. Wojciech Sadowski | | | | | | |
| | | | prof. dr hab. inż. Barbara Kościelska | | | | | | |
| Lesson types and methods of instruction | Lesson type | Lecture | Tutorial | Laboratory | Projec | t | Seminar | SUM | |
| | Number of study hours | 30.0 | 0.0 | 0.0 | 0.0 | | 15.0 | 45 | |
| | E-learning hours included: 0.0 | | | | | | | | |
| Learning activity and number of study hours | Learning activity | Participation i classes include plan | | | Self-study SUM | | SUM | | |
| | Number of study hours | 45 | | 6.0 | | 49.0 | | 100 | |
| Subject objectives | The aim of the course is to gain knowledge, skills and competences of solid state electronics and nanoeletronics. | | | | | | | | |
| Learning outcomes | Course outcome | | Subject outcome | | Method of verification | | | | |
| | K6_U11 | | Ability to prepare presentations and deliver seminars on solid state electronics and nanoelectronics. | | | [SU1] Assessment of task fulfilment | | | |
| | K6_W09 | | Knowledge of the structure and operation of basic elements of electronic systems, such as diodes and transistors. | | | [SW1] Assessment of factual knowledge | | | |
| | K6_K04 | | Ability to work in a team. | | | [SK1] Assessment of group work skills | | | |
| K6_W08 | | | Basic knowledge of solid state electronics and nanoelectronics. | | | [SW1] Assessment of factual knowledge | | | |

| Subject contents | 1. Introduction. | | | | | | |
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| | 2 Physics and proportion of colida | a review | | | | | |
| | 2. Physics and properties of solids - a review | | | | | | |
| | 2.1 Density of states in 0D, 1D, 2D and 3D materials | | | | | | |
| | 2.1. Density of states in 0D, 1D, 2D and 3D materials.2.2. Band structure of solids: free electron, nearly free electron and tight binding model. | | | | | | |
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| | the state of the s | | | | | | |
| | 2.3. Energy bands and carrier concentration in thermal equilibrium. | | | | | | |
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| | 2.4. Electrical and thermal conduction in solids: carrier transport phenomena. | | | | | | |
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| | 2.5. Kinetic phenomena in semiconductors. | | | | | | |
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| | 3. Metal-semiconductor junctions and p-n junctions. | | | | | | |
| | | | | | | | |
| | 4. Diodes: Schottky diode, p-n diode | e, MIS, MOS, tunneling diode, resona | ant-tunneling diode. | | | | |
| | 5. Transistors: bipolar, FET, hot-electron HET and THET, single-electron transistor. | | | | | | |
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| | 6. Light emitting diodes and lasers. | | | | | | |
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| | 6.1. Light emitting diodes. | | | | | | |
| | | | | | | | |
| | 6.2. Semiconductor lasers. | | | | | | |
| | C 2 Overture conside leave | | | | | | |
| | 6.3. Quantum-cascade laser. | | | | | | |
| | 7. Photodetectors and solar cells. | | | | | | |
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| | 8. Tunnel phenomena in superconductors: Josephson junction. | | | | | | |
| | 5. 12 | | | | | | |
| | 9. Spintronic devices. | | | | | | |
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| | 10. Semiconductor technology. | | | | | | |
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| | 10.1. Crystal growth and epitaxy. | | | | | | |
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| | 10.2. Film formation. | | | | | | |
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| | 10.3. Lithography and etching. | | | | | | |
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| | 10.4. Impurity doping. | | | | | | |
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| | 11. Summary. | | | | | | |
| Proroquinitos | Knowledge od mechanics, olootricits | and magnetism, basics of nanophys | sics quantum mechanics | | | | |
| Prerequisites and co-requisites | Tranomieuge ou medianics, electricity | r and magnetism, basics of hanophys | oico, quantum mechanics. | | | | |
| Assessment methods | Subject passing criteria | Passing threshold | Percentage of the final grade | | | | |
| and criteria | written exam | 50.0% | 66.0% | | | | |
| | Seminar and presence on lessons | 50.0% | 34.0% | | | | |
| | | | | | | | |

| Recommended reading | Basic literature | Aldert van der Ziel Podstawy fizyczne elektroniki ciała stałego, WNT 1980 S.O. Kasap Principles of electronic materials and devices, McGraw-Hill, 2006, 3rd ed. S.M. Sze, M.K. Lee Semiconductor Devices, Physics and Technology, John Wiley & Sons, 2012, 3rd ed. S.M. Sze, Kwok K. Ng Physics of Semiconductor Devices, John Wiley & Sons, 2007, 3rd ed. | | | |
|--|--|---|--|--|--|
| | Supplementary literature | C. Kittel <i>Wstęp do fizyki ciała stałego</i> , PWN O. Manasreh <i>Semiconductor Heterojunctions and Nanostructures</i> , McGraw Hill | | | |
| | eResources addresses | Adresy na platformie eNauczanie: Elektronika ciała stałego i nanoelektronika - Moodle ID: 39674 https://enauczanie.pg.edu.pl/moodle/course/view.php?id=39674 | | | |
| Example issues/ example questions/ tasks being completed | Crystalline structure of solids. Models of electrons in crystals. | | | | |
| | Semiconductors: band structure of semiconductors, carrier concentration; distribution functions. | | | | |
| | Kkinetic phenomenas in semiconductors. | | | | |
| | Contact phenomenas. | | | | |
| | Diodes. | | | | |
| | Transistors. | | | | |
| | Lasers. Tunneling processes in superconductors: Josephson junction. | | | | |
| Work placement | Not applicable | | | | |

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